

LM119QML

High Speed Dual Comparator

General Description

The LM119 is a precision high speed dual comparator fabricated on a single monolithic chip. It is designed to operate over a wide range of supply voltages down to a single 5V logic supply and ground. Further, it has higher gain and lower input currents than devices like the LM710. The uncommitted collector of the output stage makes the LM119 compatible with RTL, DTL and TTL as well as capable of driving lamps and relays at currents up to 25 mA.

Although designed primarily for applications requiring operation from digital logic supplies, the LM119 is fully specified for power supplies up to $\pm 15V$. It features faster response than the LM111 at the expense of higher power dissipation. However, the high speed, wide operating voltage range and low package count make the LM119 much more versatile than older devices like the LM711.

Features

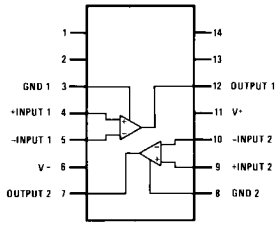
- Available with radiation guaranteed
— High Dose Rate 100 krad(Si)
- Two independent comparators
- Operates from a single 5V supply
- Typically 80 ns response time at $\pm 15V$
- Minimum fan-out of 2 each side
- Maximum input current of 1 μA over temperature
- Inputs and outputs can be isolated from system ground
- High common mode slew rate

Ordering Information

NS Part Number	SMD Part Number	NS Package Number	Package Description
LM119E/883		E20A	20LD LCC
LM119E-SMD	86014012A	E20A	20LD LCC
LM119H/883		H10C	10LD T0-100 Metal Can
LM119H-SMD	86014011A	H10C	10LD T0-100 Metal Can
LM119H-QMLV	5962-9679801VIA	H10C	10LD T0-100 Metal Can
LM119HRQMLV High Dose Rate	5962R9679801VIA 100k rd(Si)	H10C	10LD T0-100 Metal Can
LM119J/883		J14A	14LD CERDIP
LM119J-SMD	8601401CA	J14A	14LD CERDIP
LM119J-QMLV	5962-9679801VCA	J14A	14LD CERDIP
LM119JRQMLV High Dose Rate	5962R9679801VCA 100k rd(Si)	J14A	14LD CERDIP
LM119W/883		W10A	10LD CERPAK
LM119W-SMD	8601401HA	W10A	10LD CERPAK
LM119W-QMLV	5962-9679801VHA	W10A	10LD CERPAK
LM119WRQMLV High Dose Rate	5962R9679801VHA 100k rd(Si)	W10A	10LD CERPAK
LM119WG/883		WG10A	10LD Ceramic SOIC
LM119WG-QMLV	5962-9679801VXA	WG10A	10LD Ceramic SOIC
LM119WGRQMLV High Dose Rate	5962R9679801VXA 100k rd(Si)	WG10A	10LD Ceramic SOIC

Connection Diagrams

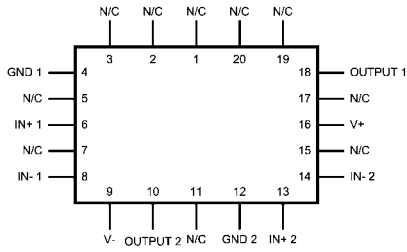
Dual-In-Line Package



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Top View
See NS Package Number J14A

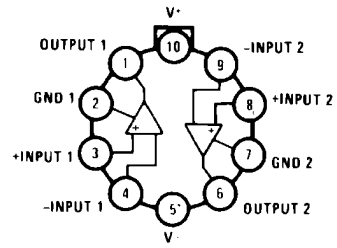
Leadless Chip Carrier



20143708

Top View
See NS Package Number E20A

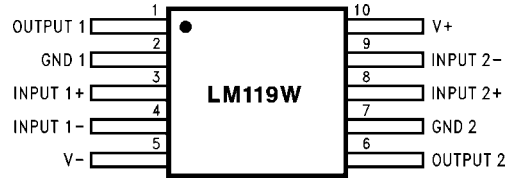
Metal Can Package



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Case is connected to pin 5 (V-)

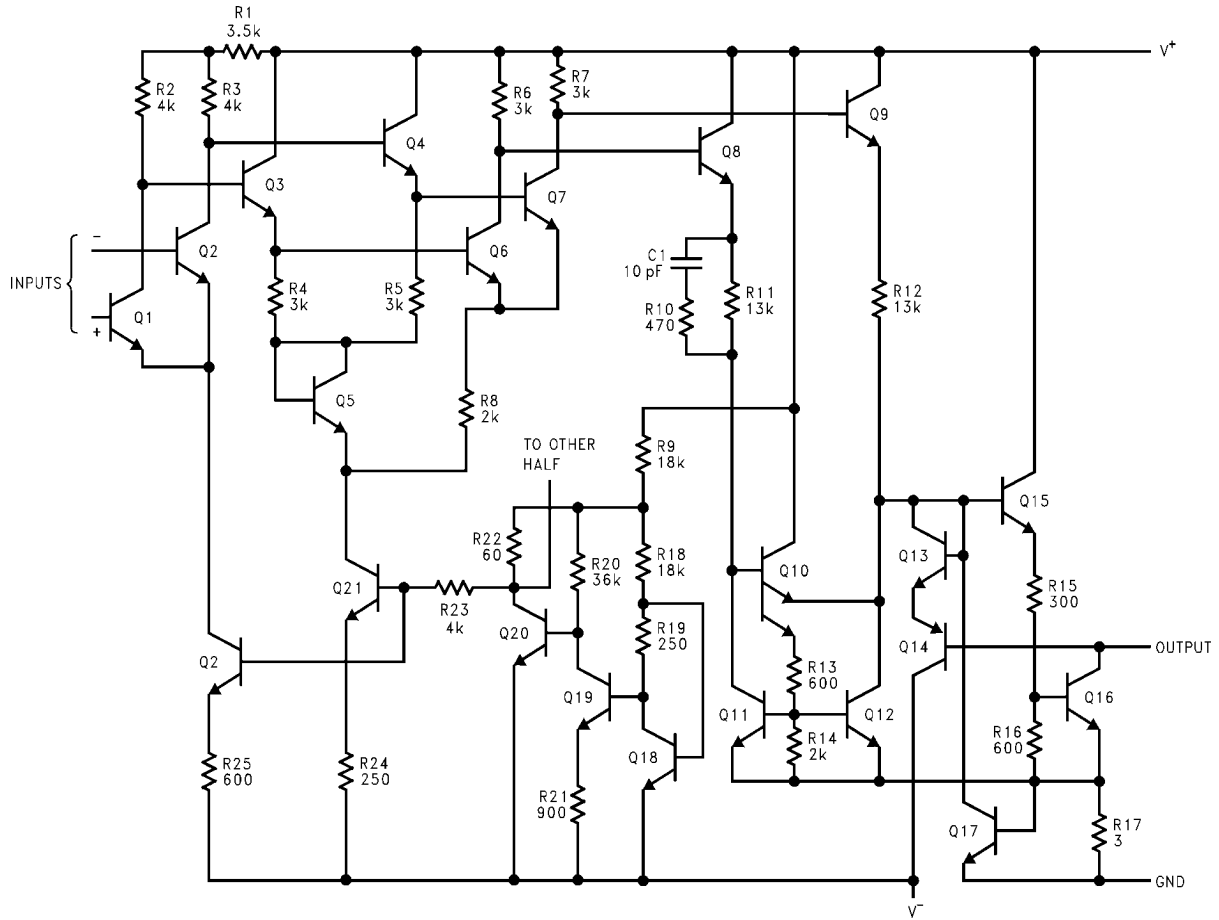
Top View
See NS Package Number H10C



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See NS Package Number W10A, WG10A

Schematic Diagram



20143701

*Do not operate the LM119 with more than 16V between GND and V+

Absolute Maximum Ratings (Note 1)

Total Supply Voltage	36V
Output to Negative Supply Voltage	36V
Ground to Negative Supply Voltage	25V
Ground to Positive Supply Voltage	18V
Differential Input Voltage	±5V
Input Voltage (Note 3)	±15V
Power Dissipation (Note 2)	500 mW
Output Short Circuit Duration	10 sec
Storage Temperature Range	-65°C ≤ T _A ≤ 150°C
Operating Ambient Temperature Range	-55°C ≤ T _A ≤ 125°C
Maximum Junction Temperature (T _J)	150°C
Lead Temperature (Soldering, 10 sec.)	260°C
Thermal Resistance	
θ_{JA}	
E Package (Still Air)	89°C/W
E Package (500LF/Min Air flow)	63°C/W
H Package (Still Air)	162°C/W
H Package (500LF/Min Air flow)	88°C/W
J Package (Still Air)	94°C/W
J Package (500LF/Min Air flow)	52°C/W
W Package (Still Air)	215°C/W
W Package (500LF/Min Air flow)	132°C/W
WG Package (Still Air)	215°C/W
WG Package (500LF/Min Air flow)	132°C/W
θ_{JC}	
E Package	5°C/W
H Package	31°C/W
J Package	11°C/W
W Package	13°C/W
WG Package	13°C/W
Package Weight	
E Package	TBD
H Package	TBD
J Package	TBD
W Package	TBD
WG Package	225mg
ESD rating (Note 4)	800V

Quality Conformance Inspection

Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

LM119/883 Electrical Characteristics

DC Parameters

The following conditions apply, unless otherwise specified. $V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups	
$+I_{CC}$	Positive Supply Current	$\pm V_{CC} = \pm 15V, V_O = \text{Low}$ $V^+ = 5.6V \text{ thru } 1.4K\Omega$			11	mA	1	
					11.5	mA	2	
$-I_{CC}$	Negative Supply Current	$\pm V_{CC} = \pm 15V, V_O = \text{Low}$ $V^+ = 5.6V \text{ thru } 1.4K\Omega$		-4.2		mA	1	
				-4.5		mA	2	
I_{Leak}	Output Leakage Current	$+V_{CC} = 15V, -V_{CC} = -1V,$ $V_{Gnd} = 0V, V_O = 35V,$ $V_I = 5mV$			1.8	μA	1	
					9.5	μA	2	
					10.0	μA	3	
I_{IB}	Input Bias Current	$\pm V_{CC} = \pm 15V$			0.475	μA	1	
					0.95	μA	2, 3	
		$+V_{CC} = 5V, -V_{CC} = 0V,$ $V_{CM} = 1.5V$			0.475	μA	1	
					.95	μA	2, 3	
V_{IO}	Input Offset Voltage	$+V_{CC} = 5V, -V_{CC} = 0V,$ $V_{CM} = 1V, R_S \leq 5K\Omega$		-3.8	3.8	mV	1	
				-6.8	6.8	mV	2, 3	
		$+V_{CC} = 5V, -V_{CC} = 0V,$ $V_{CM} = 3V, R_S \leq 5K\Omega$		-3.8	3.8	mV	1	
				-6.8	6.8	mV	2, 3	
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V,$ $R_S \leq 5K\Omega$		-3.8	3.8	mV	1	
				-6.8	6.8	mV	2, 3	
I_{IO}	Input Offset Current	$+V_{CC} = 5V, -V_{CC} = 0V, V_{CM} = 1V$		-75	75	nA	1	
				-100	100	nA	2, 3	
		$+V_{CC} = 5V, -V_{CC} = 0V, V_{CM} = 3V$		-75	75	nA	1	
				-100	100	nA	2, 3	
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V$		-75	75	nA	1	
				-100	100	nA	2, 3	
V_{Sat}	Output Saturation Voltage	$\pm V_{CC} = \pm 15V, I_O = 25mA,$ $V_I = -5mV$			1.5	V	1	
				(Note 11)	0.4	V	1, 2	
		$+V_{CC} = 5V, -V_{CC} = 0V,$ $I_O = 4.0mA$		(Note 11)	0.6	V	3	
A_V	Voltage Gain	$\pm V_{CC} = \pm 15V, \Delta V_O = 12V,$ $R_L = 1.4K\Omega$	(Note 8), (Note 9)	10.5		K	4	
				(Note 8), (Note 9)	10		K	5, 6
		$+V_{CC} = 5V, -V_{CC} = 0V,$ $\Delta V_O = 4.5V, R_L = 1.4K\Omega$	(Note 8), (Note 10)	8.0		K	4	
				(Note 8), (Note 10)	5.0		K	5
				(Note 8), (Note 10)	5.8		K	6

LM119-SMD Electrical Characteristics SMD 8601401

DC Parameters

The following conditions apply, unless otherwise specified. $V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups	
$+I_{CC}$	Positive Supply Current	$\pm V_{CC} = \pm 15V$, $V_O = \text{Low}$ $V^+ = 5.6V$ thru $1.4K\Omega$			11	mA	1	
					11.5	mA	2, 3	
$-I_{CC}$	Negative Supply Current	$\pm V_{CC} = \pm 15V$, $V_O = \text{Low}$ $V^+ = 5.6V$ thru $1.4K\Omega$			-4.2	mA	1	
					-4.5	mA	2	
					-6.0	mA	3	
I_{Leak}	Output Leakage Current	$+V_{CC} = 15V$, $-V_{CC} = -1V$, $V_{Gnd} = 0V$, $V_O = 35V$	(Note 5)		1.8	μA	1	
			(Note 5)		10	μA	2, 3	
I_{IB}	Input Bias Current	$\pm V_{CC} = \pm 15V$			0.475	μA	1	
					0.95	μA	2, 3	
		$+V_{CC} = 5V$		(Note 6)		0.475	μA	1
				(Note 6)		.95	μA	2, 3
V_{IO}	Input Offset Voltage	$+V_{CC} = 5V$, $V_{CM} = 1V$, $R_S \leq 5K\Omega$	(Note 6)	-3.8	3.8	mV	1	
			(Note 6)	-6.8	6.8	mV	2, 3	
		$+V_{CC} = 5V$, $V_{CM} = 3V$, $R_S \leq 5K\Omega$	(Note 6)	-3.8	3.8	mV	1	
			(Note 6)	-6.8	6.8	mV	2, 3	
		$\pm V_{CC} = \pm 15V$, $V_{CM} = 12V$, $R_S \leq 5K\Omega$		-3.8	3.8	mV	1	
				-6.8	6.8	mV	2, 3	
		$\pm V_{CC} = \pm 15V$, $V_{CM} = -12V$, $R_S \leq 5K\Omega$		-3.8	3.8	mV	1	
				-6.8	6.8	mV	2, 3	
I_{IO}	Input Offset Current	$+V_{CC} = 5V$, $V_{CM} = 1V$	(Note 6)	-75	75	nA	1	
			(Note 6)	-100	100	nA	2, 3	
		$+V_{CC} = 5V$, $V_{CM} = 3V$	(Note 6)	-75	75	nA	1	
			(Note 6)	-100	100	nA	2, 3	
		$\pm V_{CC} = \pm 15V$, $V_{CM} = 12V$		-75	75	nA	1	
				-100	100	nA	2, 3	
		$\pm V_{CC} = \pm 15V$, $V_{CM} = -12V$		-75	75	nA	1	
				-100	100	nA	2, 3	
V_I	Input Voltage Range	$+V_{CC} = 5V$	(Note 6), (Note 7)	1.0	3.0	V	1, 2, 3	
			(Note 7)	-12	12	V	1, 2, 3	
V_{Sat}	Output Saturation Voltage	$\pm V_{CC} = \pm 15V$, $I_O = 25mA$, $V_I \leq -5mV$	(Note 5)		1.5	V	1, 2, 3	
					0.4	V	1, 2	
					0.6	V	3	
A_V	Voltage Gain	$\pm V_{CC} = \pm 15V$, $\Delta V_O = 12V$, $R_L = 1.4K\Omega$	(Note 8)	10.5		K	4	
			(Note 8)	10		K	5, 6	
		$+V_{CC} = 5V$, $-V_{CC} = 0V$, $\Delta V_O = 4.5V$, $R_L = 1.4K\Omega$	(Note 6), (Note 8)	8.0		K	4	
			(Note 6), (Note 8)	5.0		K	5	
			(Note 6), (Note 8)	5.8		K	6	
CMRR	Common Mode Rejection Ratio	$\pm V_{CC} = \pm 15V$, $V_{CM} = \pm 12V$		80		dB	4	

LM119 Electrical Characteristics SMD 5962-9679801

DC Parameters

The following conditions apply, unless otherwise specified. $V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC} = \pm 15V, V_O = \text{Low}$ $V^+ = 5.6V \text{ thru } 1.4K\Omega$			11	mA	1
					11.5	mA	2, 3
$-I_{CC}$	Negative Supply Current	$\pm V_{CC} = \pm 15V, V_O = \text{Low}$ $V^+ = 5.6V \text{ thru } 1.4K\Omega$			-4.2	mA	1
					-4.5	mA	2
					-6.0	mA	3
I_{Leak}	Output Leakage Current	$+V_{CC} = 15V, -V_{CC} = -1V,$ $V_{Gnd} = 0V, V_O = 35V$	(Note 5)		1.8	μA	1
			(Note 5)		10	μA	2, 3
I_{IB}	Input Bias Current	$\pm V_{CC} = \pm 15V$			0.475	μA	1
					0.95	μA	2, 3
		$+V_{CC} = 5V$	(Note 6)		0.475	μA	1
			(Note 6)		.95	μA	2, 3
V_{IO}	Input Offset Voltage	$+V_{CC} = 5V, V_{CM} = 1V, R_S \leq 5K\Omega$	(Note 6)	-3.8	3.8	mV	1
			(Note 6)	-6.8	6.8	mV	2, 3
		$+V_{CC} = 5V, V_{CM} = 3V,$ $R_S \leq 5K\Omega$	(Note 6)	-3.8	3.8	mV	1
			(Note 6)	-6.8	6.8	mV	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V,$ $R_S \leq 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = -12V,$ $R_S \leq 5K\Omega$		-3.8	3.8	mV	1
				-6.8	6.8	mV	2, 3
I_{IO}	Input Offset Current	$+V_{CC} = 5V, V_{CM} = 1V$	(Note 6)	-75	75	nA	1
			(Note 6)	-100	100	nA	2, 3
		$+V_{CC} = 5V, V_{CM} = 3V$	(Note 6)	-75	75	nA	1
			(Note 6)	-100	100	nA	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = 12V$		-75	75	nA	1
				-100	100	nA	2, 3
		$\pm V_{CC} = \pm 15V, V_{CM} = -12V$		-75	75	nA	1
				-100	100	nA	2, 3
V_I	Input Voltage Range	$+V_{CC} = 5V$	(Note 6), (Note 7)	1.0	3.0	V	1, 2, 3
		$\pm V_{CC} = \pm 15V$	(Note 7)	-12	12	V	1, 2, 3
V_{Sat}	Output Saturation Voltage	$\pm V_{CC} = \pm 15V, I_O = 25mA,$ $V_I \leq -5mV$	(Note 5)		1.5	V	1, 2, 3
		$+V_{CC} = 3.5V, -V_{CC} = -1V,$ $V_I \leq -6mV, I_O \leq 3.2mA$			0.4	V	1, 2
					0.6	V	3
A_V	Voltage Gain	$\pm V_{CC} = \pm 15V, \text{Delta } V_O = 12V,$ $R_L = 1.4K\Omega$	(Note 8)	10.5		K	4
			(Note 8)	10		K	5, 6
		$+V_{CC} = 5V, -V_{CC} = 0V,$ $\text{Delta } V_O = 4.5V, R_L = 1.4K\Omega$	(Note 6), (Note 8)	8.0		K	4
			(Note 6), (Note 8)	5.0		K	5
			(Note 6), (Note 8)	5.8		K	6
CMRR	Common Mode Rejection Ratio	$\pm V_{CC} = \pm 15V, V_{CM} = \pm 12V$		80		dB	4

DC DELTA Parameters SMD 5962-9679801

The following conditions apply, unless otherwise specified.

$V_{CM} = 0V$, Delta calculations performed on QMLV devices at group B, subgroup 5 only.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
$+I_{CC}$	Positive Supply Current	$\pm V_{CC} = \pm 15V$, $V_O = \text{Low}$ $V^+ = 5.6V$ thru $1.4K\Omega$		-1.0	1.0	mA	1
$-I_{CC}$	Negative Supply Current	$\pm V_{CC} = \pm 15V$, $V_O = \text{Low}$ $V^+ = 5.6V$ thru $1.4K\Omega$		-0.5	0.5	mA	1
V_{IO}	Input Offset Voltage	$+V_{CC} = 5V$, $V_{CM} = 1V$, $R_S \leq 5K\Omega$		-0.4	0.4	mV	1

Post Radiation Parameters SMD 5962-9679801 (Note 12)

The following conditions apply, unless otherwise specified.

$V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
I_{IB}	input Bias Current	$\pm V_{CC} = \pm 15V$			1.0	μA	1
		$V_{CC} = 5V$			1.0	μA	1
V_{IO}	Input Offset Voltage	$+V_{CC} = 5V$, $V_{CM} = 1V$, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$+V_{CC} = 5V$, $V_{CM} = 3V$, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$\pm V_{CC} = \pm 15V$, $V_{CM} = 12V$, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1
		$\pm V_{CC} = \pm 15V$, $V_{CM} = -12V$, $R_S \leq 5K\Omega$		-4.0	4.0	mV	1

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{Dmax} = (T_{Jmax} - T_A) / \theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.

Note 3: For supply voltages less than $\pm 15V$ the absolute maximum input voltage is equal to the supply voltage.

Note 4: Human Body model, $1.5K\Omega$ in series with $100pF$.

Note 5: $V_I \geq 8mV$ at extremes for I_{Leak} and $V_I \leq -8mV$ at extremes for V_{Sat} (V_I to exceed V_{OS}).

Note 6: 5V differential across $+V_{CC}$ and $-V_{CC}$.

Note 7: Parameter guaranteed by V_{IO} and I_{IO} tests.

Note 8: $K = V/mV$.

Note 9: Gain is computed with an output swing from $+13.5V$ to $+1.5V$.

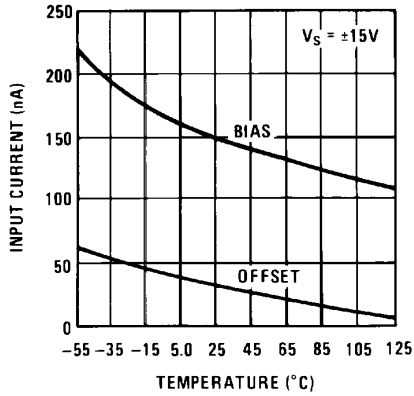
Note 10: Gain is computed with an output swing from $+5.0V$ to $+0.5V$.

Note 11: Output is monitored by measuring V_I with limits from 0 to 6mV at all temperatures

Note 12: Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics except as listed in the Post Radiation Limits Table. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in Mil-Std-883, Method 1019, Condition A.

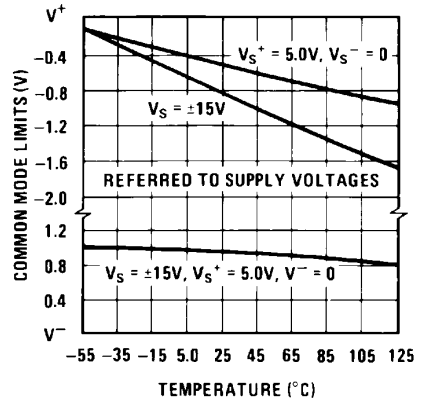
Typical Performance Characteristics

Input Currents



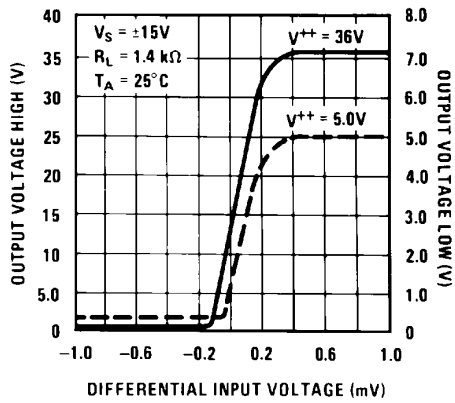
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Common Mode Limits



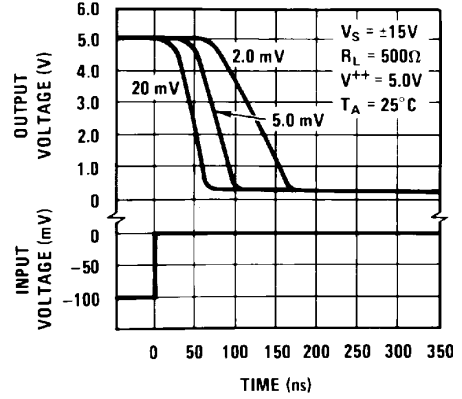
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Transfer Function



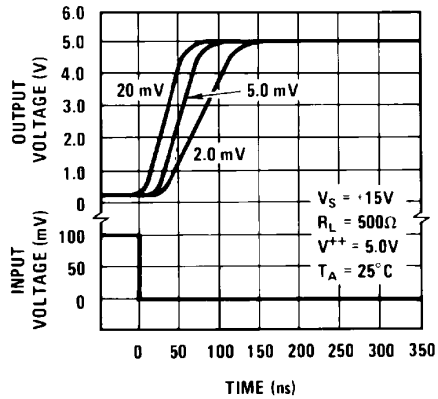
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Response Time for Various Input Overdrives



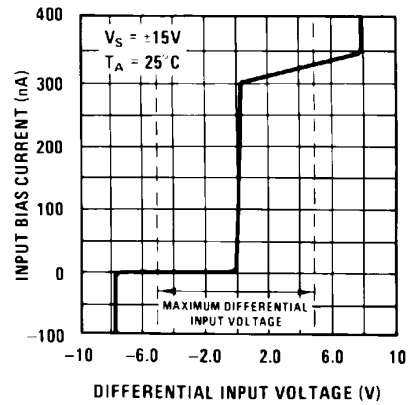
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Response Time for Various Input Overdrives



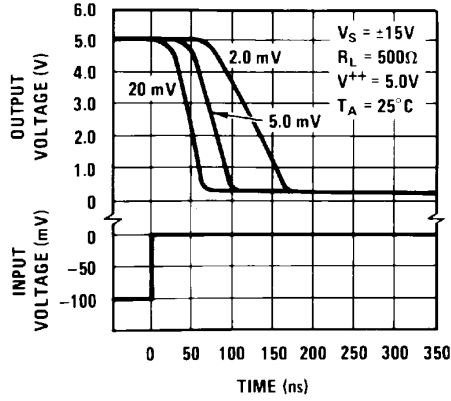
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Input Characteristics



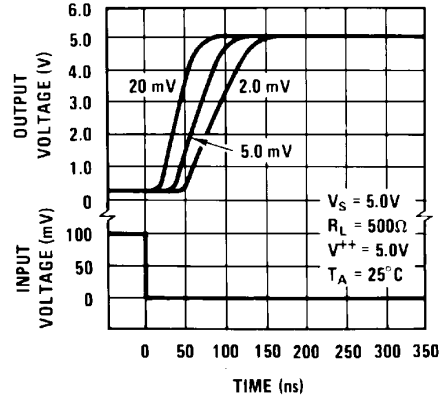
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Response Time for Various Input Overdrives



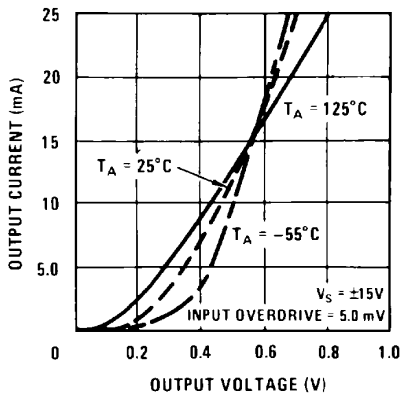
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Response Time for Various Input Overdrives



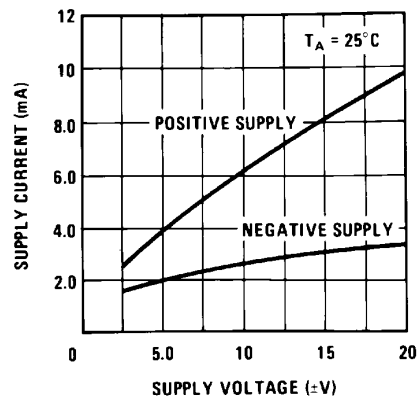
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Output Saturation Voltage



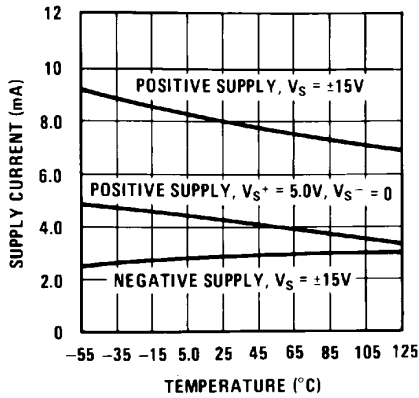
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Supply Current



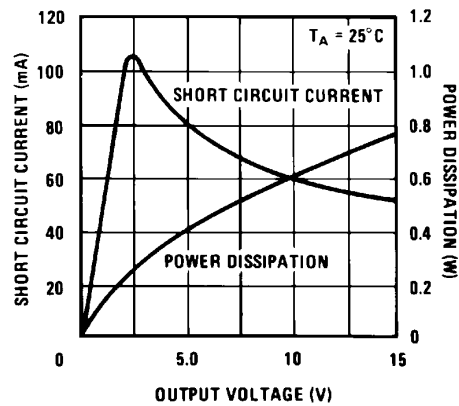
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Supply Current



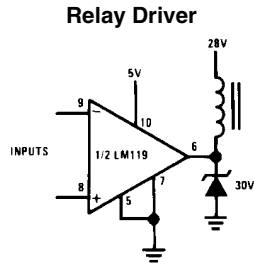
20143720

Output Limiting Characteristics



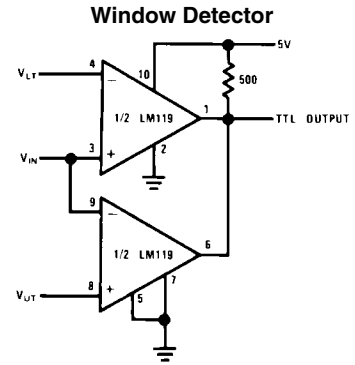
20143721

Typical Applications (Note Pin numbers are for metal can package.)



20143705

Note 13: Pin numbers are for metal can package.



20143706

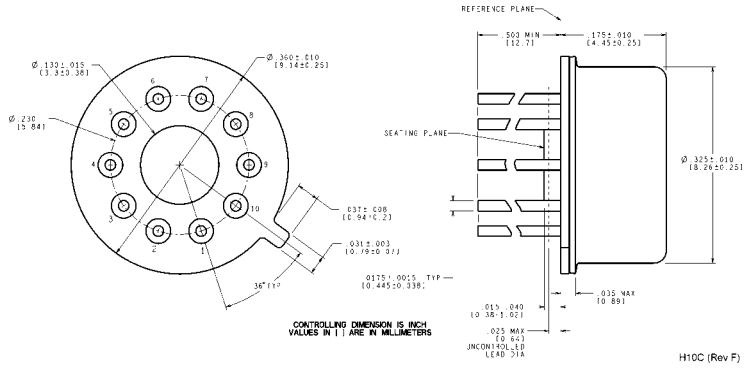
$$V_{OUT} = 5V \text{ for } V_{LT} \leq V_{IN} \leq V_{UT}$$

$$V_{OUT} = 0 \text{ for } V_{IN} \leq V_{LT} \text{ or } V_{IN} \geq V_{UT}$$

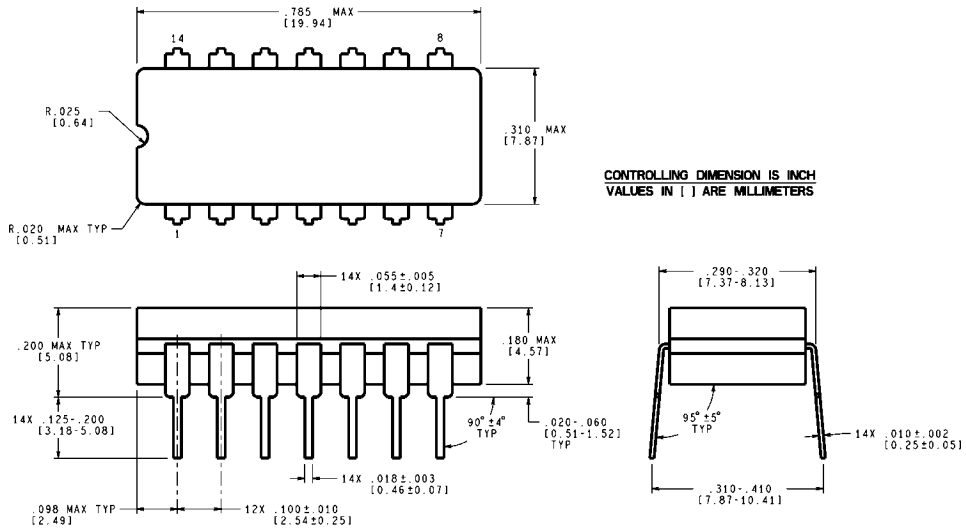
Revision History

Date Released	Revision	Section	Originator	Changes
07/24/08	A	New release to corporate format	L. Lytle	2 MDS datasheets converted into one corporate data sheet format. Added Radiation information. MDS data sheets MNLM119-X Rev. 0F1 & MDLM119-X Rev 2A2 will be archived.

Physical Dimensions inches (millimeters) unless otherwise noted



Metal Can Package (H)
NS Package Number H10C



Cavity Dual-In-Line Package (J)
NS Package Number J14A

J14A (Rev J)

Notes

LM119QML

Notes

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